TOSHIBA TCD2502C-1

TOSHIBA CCD LINEAR IMAGE SENSOR CCD(Charge Coupled Device)

T C D 2 5 0 2 C - 1

The TCD2502C-1 is a high sensitive and low dark current 5000 elements x 3 lines CCD color image sensor.

The sensor is designed for digital color copying machine and color scanner.

The device contains a row of 5000 elements x 3 lines photodiodes which provide a 16 lines/mm across a A3 size paper. The device is operated by 5V pulse, and 12 V power supply.



Number of Image Sensing Elements: 5000 elements x

3 lines

Image Sensing Element Size : 14 μ m by 14 μ m on

14 μ m centers

Photo Sensing Region : High sensitive pn photodiode

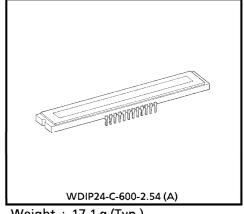
Distance Between Photodiode Array : 84 μ m (6 Lines) : 2 phase (5 V)

Package : 24 pin DIP Clock Filter : Red, Green, Blue

MAXIMUM RATINGS (Note 1)

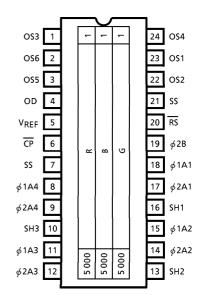
minus (Note 1)			
CHARACTERISTIC	SYMBOL	RATING	UNIT
Clock Pulse Voltage	Vφ		>
Shift Pulse Voltage	V _{SH}	-0.3~8	
Reset Pulse Voltage	VRS	-0.5 -0	
Clamp Pulse Voltage	V CP		
Power Supply Voltage	V _{OD}	-0.3~15	
	V _{REF}	-0.5 15	
Operating Temperature	T _{opr}	0~60	°C
Storage Temperature	T _{stg}	- 25∼85	°C

(Note 1): All voltage are with respect to SS terminals (Ground).



Weight: 17.1 g (Typ.)

PIN CONNECTIONS



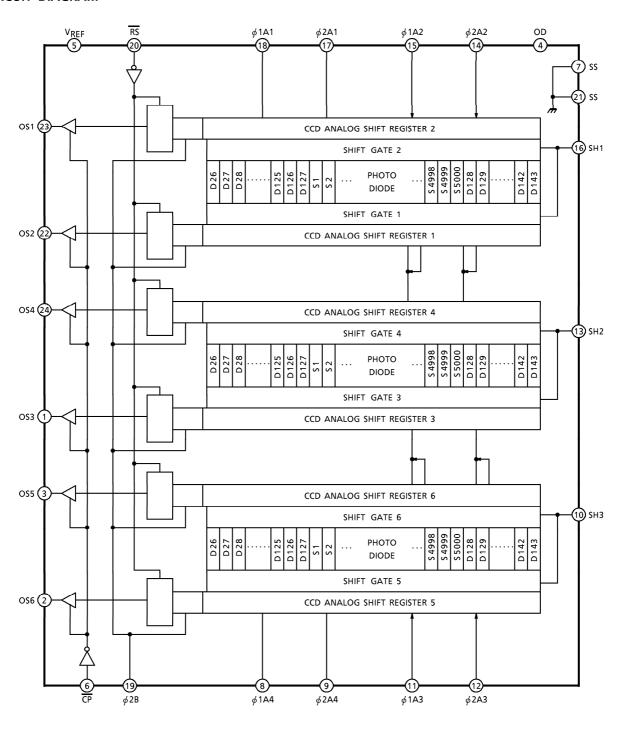
(TOP VIEW)

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CIRCUIT DIAGRAM



TOSHIBA TCD2502C-1

PIN NAMES

φ1A1,2,3,4	Clock 1	OS1	Signal Output 1 (Green)
φ2A1,2,3,4	Clock 2	OS2	Signal Output 2 (Green)
φ2B	Final Stage Clock	OS3	Signal Output 3 (Blue)
RS	Reset Gate	OS4	Signal Output 4 (Blue)
SS	Ground	OS5	Signal Output 5 (Red)
OD	Power Supply	OS6	Signal Output 6 (Red)
SH	Shift Gate	V _{REF}	Clamp Reference Voltage
		CP	Clamp Gate

OPTICAL / ELECTRICAL CHARACTERISTICS

(Ta = 25°C, V_{OD} = 12 V, V $_{\phi}$ = V $_{\overline{RS}}$ = V $_{\overline{CP}}$ = V_{SH} = 5 V (pulse), f $_{\phi}$ = 1.0 MHz, f $_{\overline{RS}}$ = 1.0 MHz, LOAD RESISTANCE = 100 k $_{\Omega}$, t_{INT} (INTEGRATION TIME) = 10 ms,

LIGHT SOURCE = A LIGHT SOURCE + CM500S FILTER (t = 1.0 mm))

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	NOTE	
Sensitivity (Red)	RR	4.6	6.7	8.8			
Sensitivity (Green)	RG	5.8	8.4	11.0	V / Ix·s	(Note 2)	
Sensitivity (Blue)	RB	1.9	2.8	3.7			
Photo Response Non Uniformity	PRNU (1)	_	10	35	%	(Note 3)	
	PRNU (3)	_	10	15	mV	(Note 4)	
Saturation Output Voltage	V _{SAT} (B)	1.0	1.2	_	V	(Note 5)	
	VSAT (R, G)	2.0	2.5	_]		
Saturation Exposure	SE	0.18	0.30	_	lx•s	(Note 6)	
Dark Signal Voltage	V _{DRK}	_	1	5	mV	(Note 7)	
Dark Signal Non Uniformity	DSNU	_	2	10	mV	(Note 8)	
Total Transfer Efficiency	TTE	92	_	_	%		
Output Impedance	Z _o	_	0.5	1.0	kΩ		
Current Dissipation	loD	_	30	45	A		
	I _{REF}	_	20	30	mA		
DC Offset Voltage	Vos	4.5	6.0	7.5	V	(Note 9)	

- (Note 2): Sensitivity is defined for each color of signal outputs average when the photosensitive surface is applied with the light of uniform illumination and uniform color temperature.
- (Note 3): PRNU (1) is defined for each color on a single chip by the expressions below when the photosensitive surface is applied with the light of uniform illumination and uniform color temperature.

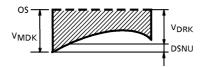
PRNU (1) =
$$\frac{\Delta \chi}{\overline{\chi}}$$
 × 100 (%)

Where $\overline{\chi}$ is average of total signal outputs and $\Delta \chi$ is the maximum deviation from $\overline{\chi}$.

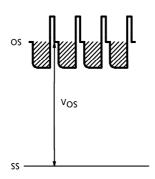
- (Note 4): PRNU (3) is defined as maximum voltage with next pixel, where measured 5% of SE (Typ.).
- (Note 5): V_{SAT} is defined as minimum Saturation Output voltage of all effective pixels.

(Note 6) : Definition of SE : SE =
$$\frac{V_{SAT}}{R_{G}}$$

- (Note 7): VDRK is defined as average dark signal voltage of all effective pixels.
- (Note 8) : DSNU is defined as different voltage between V_{DRK} and V_{MDK} , when V_{MDK} is maximum dark voltage.



(Note 9): DC Signal Output Voltage is defined as follows:



OPERATING CONDITION

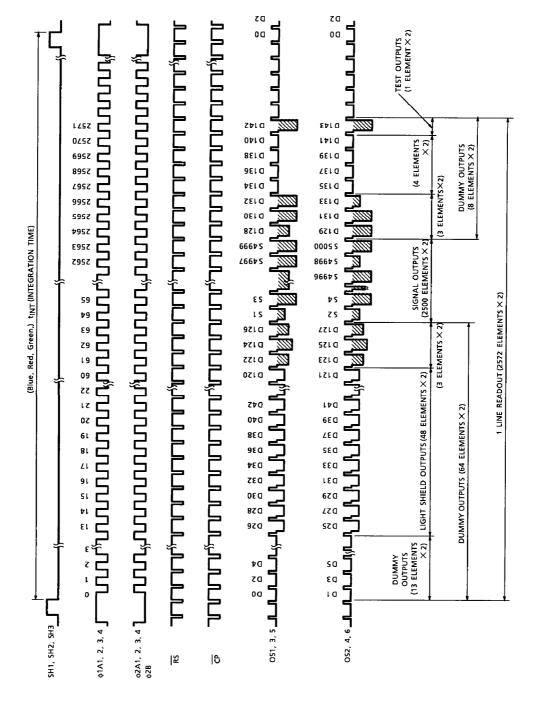
CHARACTERISTIC		SYMBOL	MIN.	TYP.	MAX.	UNIT
Clark Bules Valtage	"H" Level)//A	4.5	5.0	5.5	V
Clock Pulse Voltage	"L" Level	VφA	0	_	0.5	
Final Stage Clock Bulse Voltage	"H" Level	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	4.5	5.0	5.5	V
I stage clock ruise voitage	nal Stage Clock Pulse Voltage "L" Level V∮B	VφB	0	_	0.5	
Shift Pulse Voltage (Note 10)	"H" Level	V _{SH}	V <i>∮</i> A"H" - 0.5	Vφ Α" H"	Vφ Α" H"	V
	"L" Level		0	_	0.5	
Reset Pulse Voltage	"H" Level	\/ = 6	4.5	5.0	5.5	v
	"L" Level	VRS	0	_	0.5	'
Clamp Pulse Voltage	"H" Level	\/—	4.5	5.0	5.5	V
	"L" Level	VCP	0	_	0.5	\ \
Clamp Reference Voltage	(Note 11)	V _{REF}	11.4	12.0	V _{OD}	V
Power Supply Voltage	(Note 11)	V _{OD}	11.4	12.0	13.0	V

(Note 10) : $V_\phi A''H''$ means the high-level voltage of $V_\phi A$ when SH pulse is high level. (Note 11) : V_{OD} - V_{REF} should be 0.5 V or less.

CLOCK CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Clock Pulse Frequency	f_ϕ	_	1.0	8	MHz
Reset Pulse Frequency	fRS	_	1.0	8	MHz
Clamp Pulse Frequency	f <u>C</u> P	_	1.0	8	MHz
Clock Capacitance	C∳A1, 4	_	500	_	pF
	C <i>ϕ</i> A2, 3	_	400	_	
Final Stage Clock Capacitance	CøB	_	40	_	pF
Reset Gate Capacitance	CRS	_	40	_	pF
Shift Gate Capacitance	C _{SH}	_	250	_	pF
Clamp Gate Capacitance	CCP	_	40	_	pF

TIMING CHART

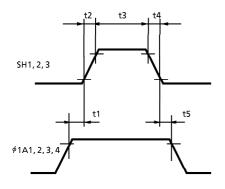


TCD2502C-1-6

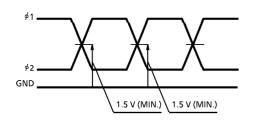
TOSHIBA TCD2502C-1

TIMING REQUIREMENTS

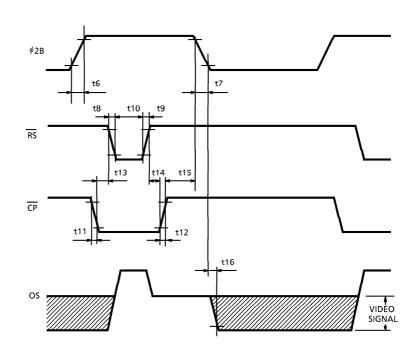
SH, ϕ 1 TIMING



 ϕ 1, ϕ 2 CROSS POINT



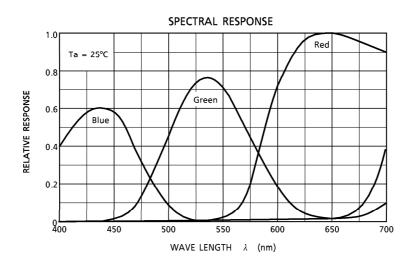
 ϕ 2B, \overline{RS} , \overline{CP} , OS, TIMING



CHARACTERISTIC		SYMBOL	MIN.	TYP. (Note 12)	MAX.	UNIT
Pulse Timing of SH and ϕ 1A		t1, t5	0	100	_	ns
SH Pulse Rise Time, Fall Time		t2, t4	0	50	_	ns
SH Pulse Width		t3	800	1000	_	ns
ϕ 2B Pulse Rise Time, Fall Time		t6, t7	0	100	_	ns
RS Pulse Rise Time, Fall Time		t8, t9	0	20	_	ns
RS Pulse Width		t10	25	50	_	ns
CP Pulse Rise Time, Fall Time		t11, t12	0	20	_	ns
Pulse Timing of RS and CP		t13	0	20	_	20
		t14	25	50	_	ns
Pulse Timing of $\overline{\sf CP}$ and ϕ 2B		t15	20	50	_	ns
Video Data Delay Time	(Note 13)	t16	_	30	_	ns

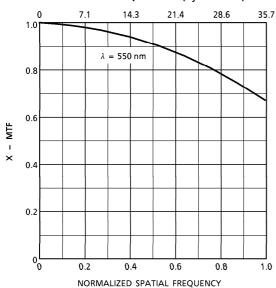
(Note 12) : TYP. is the case of f\$\overline{RS}\$ = 1 MHz. (Note 13) : Load Resistance is 100 k\$\Omega\$.

TYPICAL PERFORMANCE CURVES



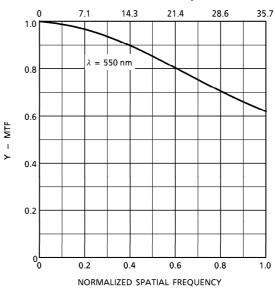
MODULATION TRANSFER FUNCTION OF X-DIRECTION

SPATIAL FREQUENCY (Cycles/mm)

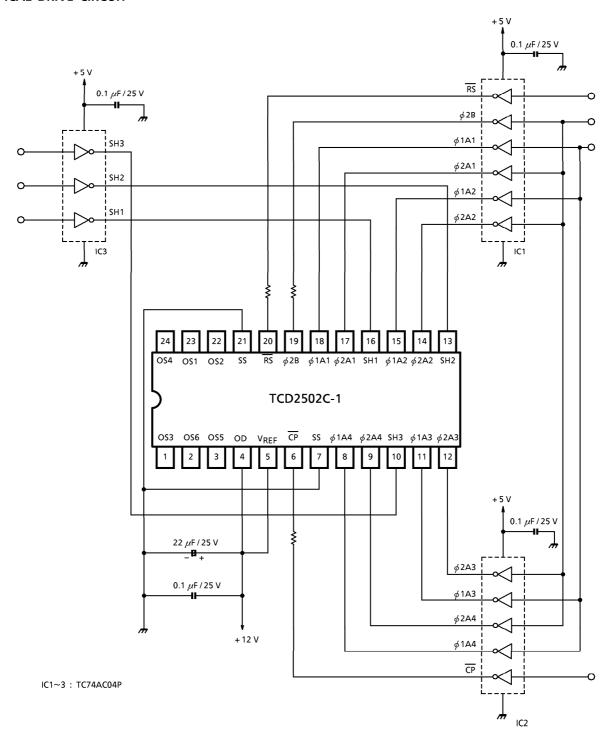


MODULATION TRANSFER FUNCTION OF Y-DIRECTION

SPATIAL FREQUENCY (Cycles/mm)



TYPICAL DRIVE CIRCUIT



CAUTION

1. Window Glass

The dust and stain on the glass window of the package degrade optical performance of CCD sensor.

Keep the glass window clean by saturating a cotton swab in alcohol and lightly wiping the surface, and allow the glass to dry, by blowing with filtered dry N₂.

Care should be taken to avoid mechanical or thermal shock because the glass window is easily to damage.

2. Electrostatic Breakdown

Store in shorting clip or in conductive foam to avoid electrostatic breakdown.

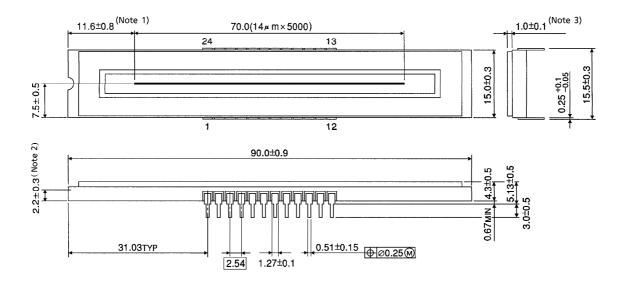
3. Incident Light

CCD sensor is sensitive to infrared light.

Note that infrared light component degrades resolution and PRNU of CCD sensor.

OUTLINE DRAWING WDIP24-C-600-2.54 (A)

Unit in mm



(Note 1): No. 1 SENSOR ELEMENT (S1) TO EDGE OF PACKAGE.

(Note 2): TOP OF CHIP TO BOTTOM OF PACKAGE.

(Note 3): GLASS THICKNES (n = 1.5)

Weight: 17.1 g (Typ.)